NSN 5961-01-518-9803

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-518-9803 **Inclosure Material:** Glass **Overall Length:** Between 0.140 inches and 0.195 inches **Terminal Length:** Between 0.900 inches and 1.300 inches **Overall Diameter:** Between 0.135 inches and 0.185 inches **Function For Which Designed:** Transient suppressor **End Application:** Mmrt **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 64.6 breakdown voltage, dc and 51.7 working peak reverse voltage **Current Rating Per Characteristic:** 15.40 amperes source cutoff current universal **Power Rating Per Characteristic:** 1500.0 watts small-signal output power, common-base horsepower metric **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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